NTST30120CT, NTSJ30120CTG, NTSB30120CT-1G, NTSB30120CTG, NTSB30120CTT4G

Very Low Forward Voltage Trench-based Schottky Rectifier

Exceptionally Low $V_F = 0.50$ V at $I_F = 5$ A

Features

- Fine Lithography Trench-based Schottky Technology for Very Low Forward Voltage and Low Leakage
- Fast Switching with Exceptional Temperature Stability
- Low Power Loss and Lower Operating Temperature
- Higher Efficiency for Achieving Regulatory Compliance
- Low Thermal Resistance
- High Surge Capability
- Pb-Free and Halide-Free Packages are Available

Typical Applications

- Switching Power Supplies including Notebook / Netbook Adapters, ATX and Flat Panel Display
- High Frequency and DC-DC Converters
- Freewheeling and OR-ing diodes
- Reverse Battery Protection
- Instrumentation

Mechanical Characteristics

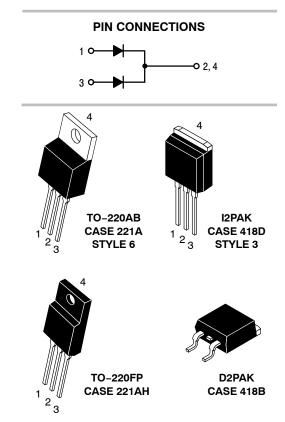
- Case: Epoxy, Molded
- Epoxy Meets Flammability Rating UL 94-0 @ 0.125 in
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Maximum for 10 sec



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VERY LOW FORWARD VOLTAGE, LOW LEAKAGE SCHOTTKY BARRIER RECTIFIERS 30 AMPERES, 120 VOLTS



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

NTST30120CT, NTSJ30120CTG, NTSB30120CT-1G, NTSB30120CTG, NTSB30120CTT4G

MAXIMUM RATINGS

| Rating | | Symbol | Value | Unit |
|--|-------------------------|--|-------------|------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | | V _{RRM} V _{RWM} V _R | 120 | V |
| Average Rectified Forward Current (Rated V_R , T_C = 125°C) | Per device Per diode | I _{F(AV)} | 30 15 | A |
| Peak Repetitive Forward Current (Rated V _R , Square Wave, 20 kHz, T _C = 130°C) | Per device Per diode | I _{FRM} | 60 30 | A |
| Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz) | | I _{FSM} | 150 | A |
| Operating Junction Temperature | | TJ | -40 to +150 | °C |
| Storage Temperature | | T _{stg} | -40 to +150 | °C |
| Voltage Rate of Change (Rated V _R) | | dv/dt | 10,000 | V/μs |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

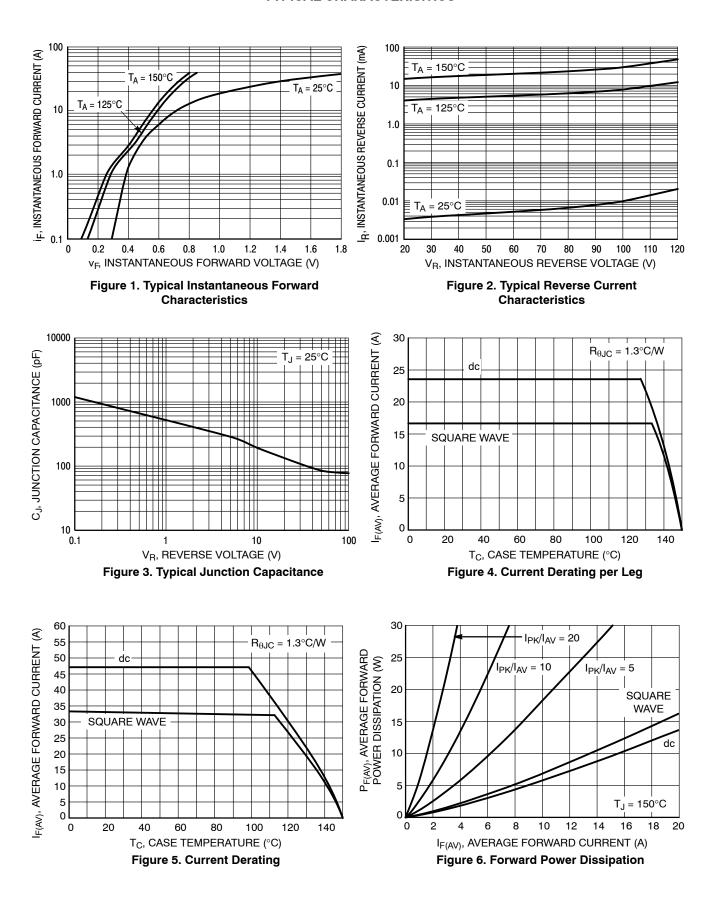
| Rating | Symbol | NTST30120CTG NTSB30120CT-1G | NTSB30120CTG | NTSJ30120CTG | Unit |
|---|-------------------------------|--------------------------------|--------------|--------------|--------------|
| Maximum Thermal Resistance per Diode Junction-to-Case Junction-to-Ambient | $R_{	heta JC} \ R_{	heta JA}$ | 2.5 70 | 1.14 46.6 | 4.05 105 | °C/W °C/W |

ELECTRICAL CHARACTERISTICS (Per Leg unless otherwise noted)

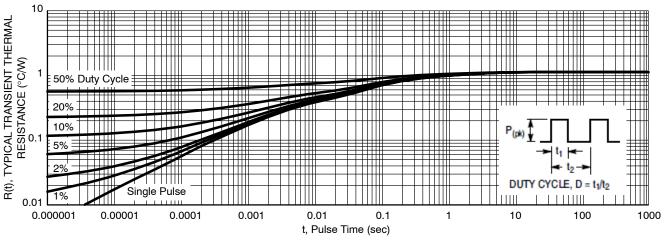
| Rating | Symbol | Тур | Мах | Unit |
|---|----------------|----------------------|----------------|----------|
| | v _F | 0.56 0.71 0.90 | - - 1.08 | V |
| | | 0.50 0.60 0.68 | _ _ 0.76 | |
| Maximum Instantaneous Reverse Current (Note 1) $(V_R = 90 \text{ V}, T_J = 25^{\circ}\text{C})$ $(V_R = 90 \text{ V}, T_J = 125^{\circ}\text{C})$ | I _R | 16 11 | _ | μA mA |
| (Rated dc Voltage, $T_J = 25^{\circ}C$) (Rated dc Voltage, $T_J = 125^{\circ}C$) | | _ 25 | 800 100 | μA mA |

1. Pulse Test: Pulse Width = 300 $\mu s,$ Duty Cycle \leq 2.0%

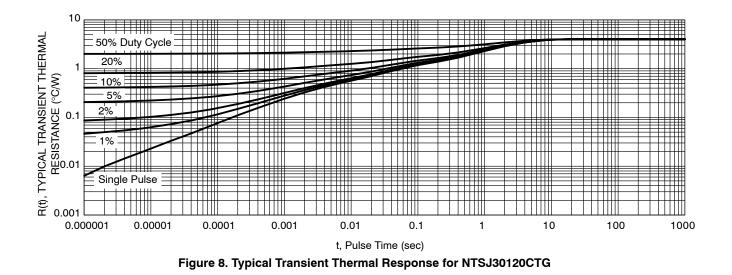
NTST30120CT, NTSJ30120CTG, NTSB30120CT-1G, NTSB30120CTG, NTSB30120CTT4G TYPICAL CHARACTERISITICS



NTST30120CT, NTSJ30120CTG, NTSB30120CT-1G, NTSB30120CTG, NTSB30120CTT4G **TYPICAL CHARACTERISITICS**







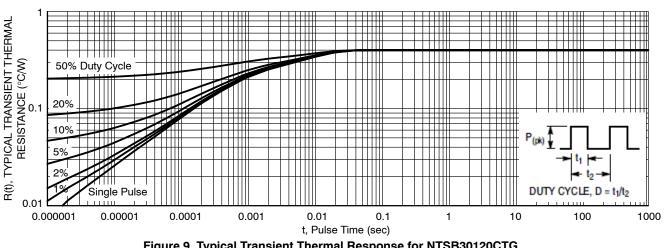


Figure 9. Typical Transient Thermal Response for NTSB30120CTG

NTST30120CT, NTSJ30120CTG, NTSB30120CT-1G, NTSB30120CTG, NTSB30120CTT4G

ORDERING INFORMATION

| Device | Package | Shipping | |
|----------------|---------------------------------|-------------------|--|
| NTST30120CTG | TO-220AB (Pb-Free) | 50 Units / Rail | |
| NTSJ30120CTG | TO-220FP (Halide-Free) | 50 Units / Rail | |
| NTSB30120CT-1G | l ² PAK (Pb–Free) | 50 Units / Rail | |
| NTSB30120CTG | D ² PAK (Pb–Free) | 50 Units / Rail | |
| NTSB30120CTT4G | D ² PAK (Pb–Free) | 800 / Tape & Reel | |

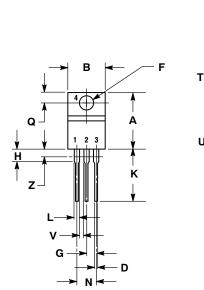
AYWW AYWW TS30120CG AYWW AYWW TS30120CG TS30120Cx TS30120CG AKA AKA AKA AKA 1 、 $\overline{1}$ TO-220AB TO-220FP I²PAK D²PAK

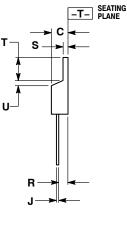
MARKING DIAGRAMS

A = Assembly Location

- Y = Year
- WW = Work Week
- AKA = Polarity Designator
- x = G or H
- G = Pb-Free Package
- H = Halide-Free Package

NTST30120CT, NTSJ30120CTG, NTSB30120CT-1G, NTSB30120CTG, NTSB30120CTT4G PACKAGE DIMENSIONS





TO-220 CASE 221A-09 **ISSUE AF**

NOTES:

1. 2. 3.

IES: DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

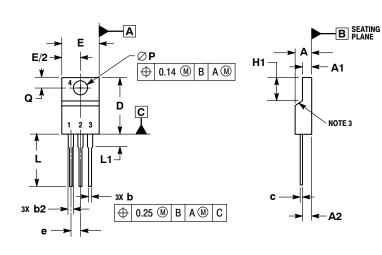
| | INCHES | | MILLIN | IILLIMETERS | |
|-----|--------|-------|--------|-------------|--|
| DIM | MIN | MAX | MIN | MAX | |
| Α | 0.570 | 0.620 | 14.48 | 15.75 | |
| в | 0.380 | 0.405 | 9.66 | 10.28 | |
| c | 0.160 | 0.190 | 4.07 | 4.82 | |
| D | 0.025 | 0.035 | 0.64 | 0.88 | |
| F | 0.142 | 0.161 | 3.61 | 4.09 | |
| G | 0.095 | 0.105 | 2.42 | 2.66 | |
| Η | 0.110 | 0.155 | 2.80 | 3.93 | |
| - | 0.014 | 0.025 | 0.36 | 0.64 | |
| Κ | 0.500 | 0.562 | 12.70 | 14.27 | |
| L | 0.045 | 0.060 | 1.15 | 1.52 | |
| Ν | 0.190 | 0.210 | 4.83 | 5.33 | |
| Ø | 0.100 | 0.120 | 2.54 | 3.04 | |
| R | 0.080 | 0.110 | 2.04 | 2.79 | |
| S | 0.045 | 0.055 | 1.15 | 1.39 | |
| Т | 0.235 | 0.255 | 5.97 | 6.47 | |
| U | 0.000 | 0.050 | 0.00 | 1.27 | |
| ۷ | 0.045 | | 1.15 | | |
| Ζ | | 0.080 | | 2.04 | |

STYLE 6:

PIN 1. ANODE 2. CATHODE

3. ANODE 4 CATHODE

TO-220 FULLPACK, 3-LEAD CASE 221AH **ISSUE B**



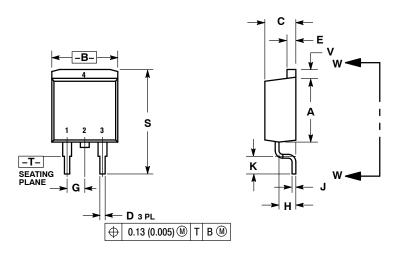
NOTES:

- DIES:
 DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 CONTOUR UNCONTROLLED IN THIS AREA.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH AND GATE PROTRUSIONS. MOLD FLASH AND GATE PROTRUSIONS NOT TO EXCEED 0.13 PER SIDE. THESE DIMENSIONS ARE TO BE MEASURED AT OUTERMOST EXTREME OF THE PLASTIC BODY.
- 5. DIMENSION b2 DOES NOT INCLUDE DAMBAR PROTRUSION. LEAD WIDTH INCLUDING PROTRUSION SHALL NOT EXCEED 2.00.

| | MILLIMETERS | | |
|-----|-------------|-------|--|
| DIM | MIN MAX | | |
| Α | 4.30 | 4.70 | |
| A1 | 2.50 | 2.90 | |
| A2 | 2.50 | 2.70 | |
| b | 0.54 | 0.84 | |
| b2 | 1.10 | 1.40 | |
| C | 0.49 | 0.79 | |
| D | 14.70 | 15.30 | |
| Ε | 9.70 | 10.30 | |
| e | 2.54 BSC | | |
| H1 | 6.70 | 7.10 | |
| L | 12.70 | 14.73 | |
| L1 | | 2.80 | |
| Ρ | 3.00 | 3.40 | |
| Q | 2.80 | 3.20 | |

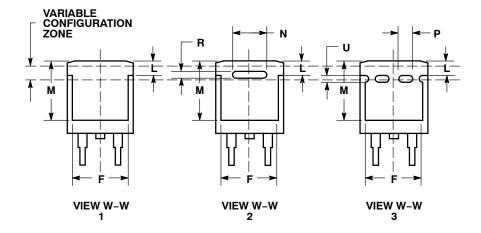
NTST30120CT, NTSJ30120CTG, NTSB30120CT-1G, NTSB30120CTG, NTSB30120CTT4G PACKAGE DIMENSIONS

D²PAK 3 CASE 418B-04 ISSUE K

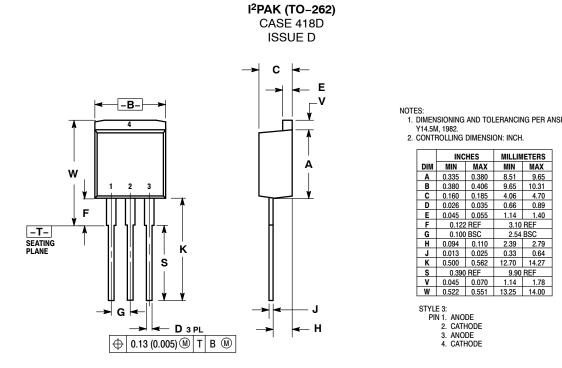


NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. 418B-01 THRU 418B-03 OBSOLETE, NEW STANDARD 418B-04.

| | INCHES | | MILLIN | IETERS |
|-----|-----------|--------------|-------------|--------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 0.340 | 0.380 | 8.64 | 9.65 |
| В | 0.380 | 0.405 | 9.65 | 10.29 |
| С | 0.160 | 0.190 | 4.06 | 4.83 |
| D | 0.020 | 0.035 | 0.51 | 0.89 |
| Е | 0.045 | 0.055 | 1.14 | 1.40 |
| F | 0.310 | 0.350 | 7.87 | 8.89 |
| G | 0.100 BSC | | 2.54 BSC | |
| Н | 0.080 | 0.110 | 2.03 | 2.79 |
| J | 0.018 | 0.025 | 0.46 | 0.64 |
| Κ | 0.090 | 0.110 | 2.29 | 2.79 |
| L | 0.052 | 0.072 | 1.32 | 1.83 |
| М | 0.280 | 0.320 | 7.11 | 8.13 |
| Ν | 0.197 REF | | 5.00 REF | |
| Ρ | 0.079 | REF | EF 2.00 REF | |
| R | 0.039 | 9 REF 0.99 R | | REF |
| S | 0.575 | 0.625 | 14.60 | 15.88 |
| ٧ | 0.045 | 0.055 | 1.14 | 1.40 |



NTST30120CT, NTSJ30120CTG, NTSB30120CT-1G, NTSB30120CTG, NTSB30120CTT4G PACKAGE DIMENSIONS



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MILLIMETERS

MIN MAX

9.65

4.70

0.89

1.40

0.64

1.78

8.51

9.65 10.31

4.06

0.66

1.14

2.39 2.79

0.33

3.10 REF

2.54 BSC

9.90 REF

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